



# High Energy Density Solid State Polymer Capacitors for Space Applications

By

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# Power Systems for Deep Space Exploration

Deep space missions to planetary bodies require electrical components with both low and high temperature survivability. Missions to the surface of Europa, permanently shadowed craters on the Moon, small bodies, and comets will be exposed to temperatures below  $-180^{\circ}\text{C}$ .

Cryogenic environments, combined with high temperature, cosmic radiation and spacecraft generated radiation when using Dynamic Radioisotope Power Systems (DRPS) such as Stirling Engines, impose significant limitations on the choice of electrical components.

One of the largest components in Power Processing Units (PPUs) are Energy Buffer and DC-link capacitors that are used to minimize ripple current, voltage fluctuations and transient suppression.

In addition to operating in extreme temperature and radiation environments, long life, high reliability, high energy density and specific energy to reduce size and weight, are desirable capacitor properties.

# Commercially Available Capacitor Technologies

## For Energy Buffer, DC-link, and Pulse Power Applications

### Polymer Film Capacitors

Chosen for their high stability of dielectric properties with temperature and voltage,  
Large and heavy especially for lower voltage applications  
Temperature range 105C-125C  
Degrade in the presence of radiation

### Ceramic Capacitors

High operating temperature  
High voltage and high microfarad parts are large and heavy  
Poor capacitance stability with temperature especially at cryogenic temperatures  
Large drop of capacitance with applied voltage  
Large ceramic capacitors can microcrack and short in DC-link and Pulse Power applications

### Tantalum Capacitors

High operating temperature  
Not available in high voltages  
About 10X increase in ESR at cryogenic temperatures



# NanoLam™ : A Disruptive Polymer Capacitor Technology

## Conventional Polymer Capacitor Supply Chain

Three Different Independent Industries are involved

### Film Extrusion

A Handful of OEMs Worldwide



### Electrode Metallization

A Small Number OEMs Worldwide



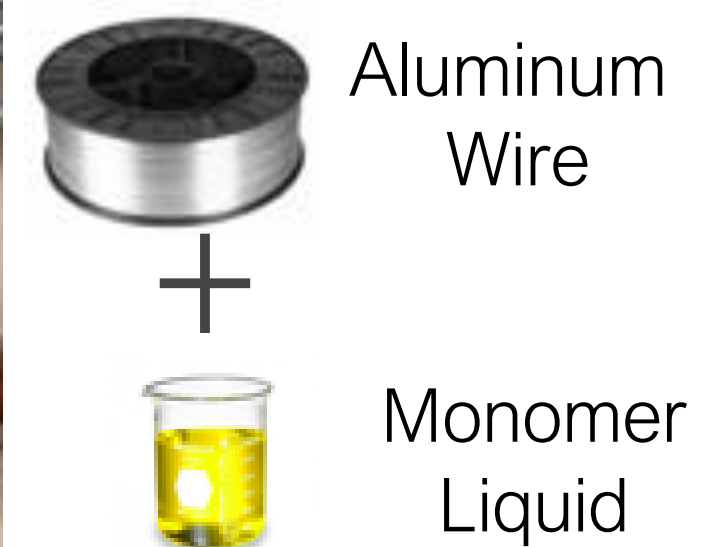
### Capacitor OEMs

100s of capacitor manufacturers worldwide utilize the same polymer films, thus limiting the ability to differentiate and innovate



## NanoLam™ Capacitor Manufacturing Process

Single Step Process Using two Materials to Produce 70sq.ft. of Nanolaminate Composite that is Processed into Capacitors

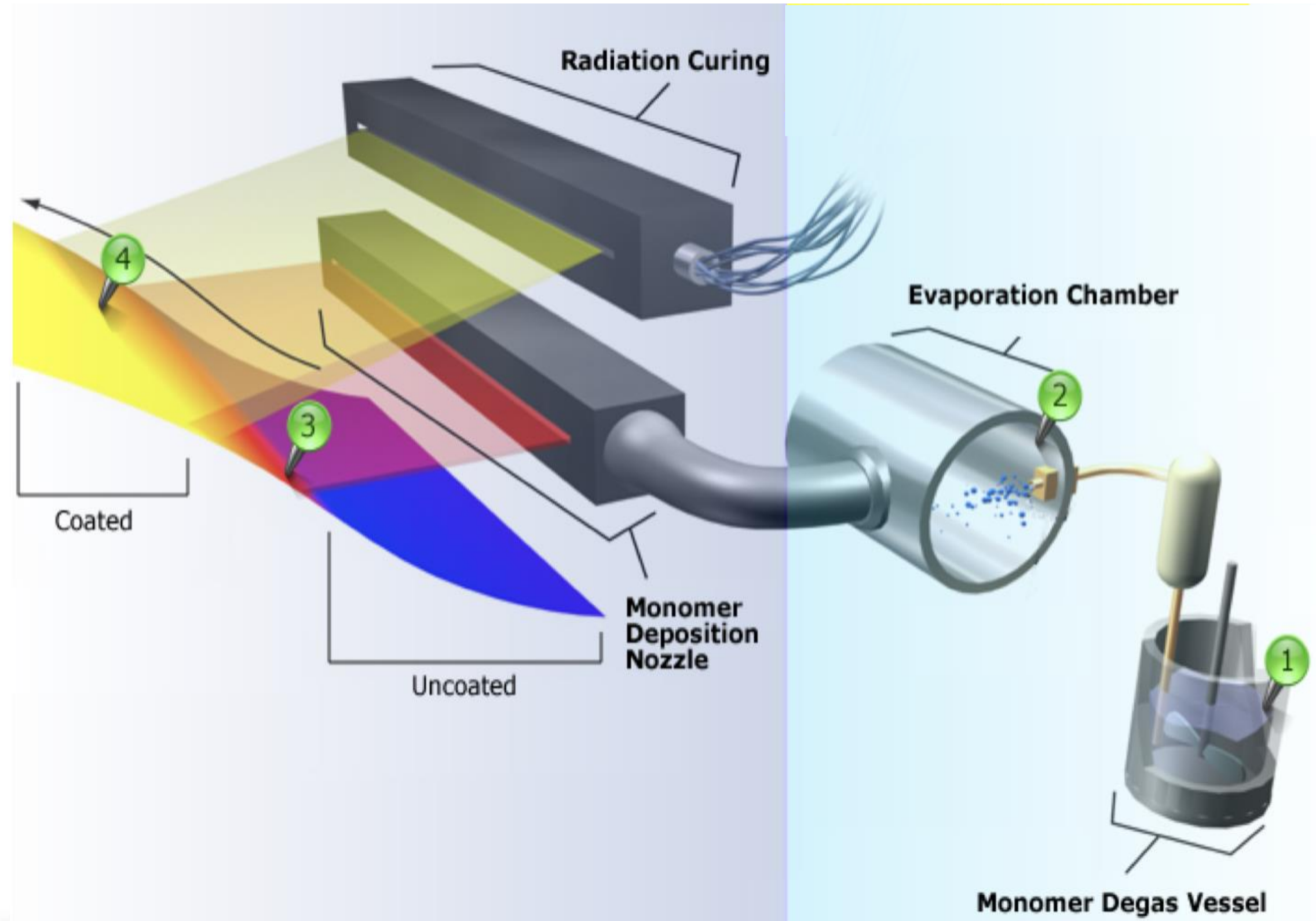


Complete Control of all Key Capacitor Properties

- Polymer Chemistry
  - High Temperature Polymers
  - Energy Storage (dielectric constant)
  - Self-healing Properties
  - Operating Temperature
  - Glass Transition Temperature
- Dielectric Thickness (100nm and higher)
- Electrode Design and Metal Thickness



A Unique and Novel Element of the NanoLam Technology is the Ability to Form 1000s of Highly Uniform Nanothick Polymer Dielectric Layers in the Vacuum on a Web or a Rotating Process Drum at speeds of 100s ft/min





# Products Developed By Sigma Technologies Based on NanoLam™ Technology Prior to Spinning Off Polycharge America Inc.

Developed low voltage SMD solid state polymer multilayer (PML) capacitors that were licensed to Panasonic and Rubycon



Functionalized textiles for heat management with superhydrophobic properties



Heat Management Applications



Nanoflake aluminum pigment used in inks and paints.



Air and Moisture Barrier Applications



Size/w.v.	25V.DC	50V.DC	100V.DC
<b>1608</b> inch code 0603	0.033 $\mu$ F	0.001→0.01 $\mu$ F	
<b>2012</b> inch code 0805	0.047→0.15 $\mu$ F	0.015→0.047 $\mu$ F	
<b>3216</b> inch code 1206	0.22→1.0 $\mu$ F	0.068→0.33 $\mu$ F	0.001→0.047 $\mu$ F
<b>3225</b> inch code 1210	1.5→2.2 $\mu$ F	0.47→0.68 $\mu$ F	0.068→0.1 $\mu$ F
<b>4532</b> inch code 1812	3.3→6.8 $\mu$ F	1.0→2.2 $\mu$ F	
<b>5750</b> inch code 2220	10→15 $\mu$ F	3.3→4.7 $\mu$ F	

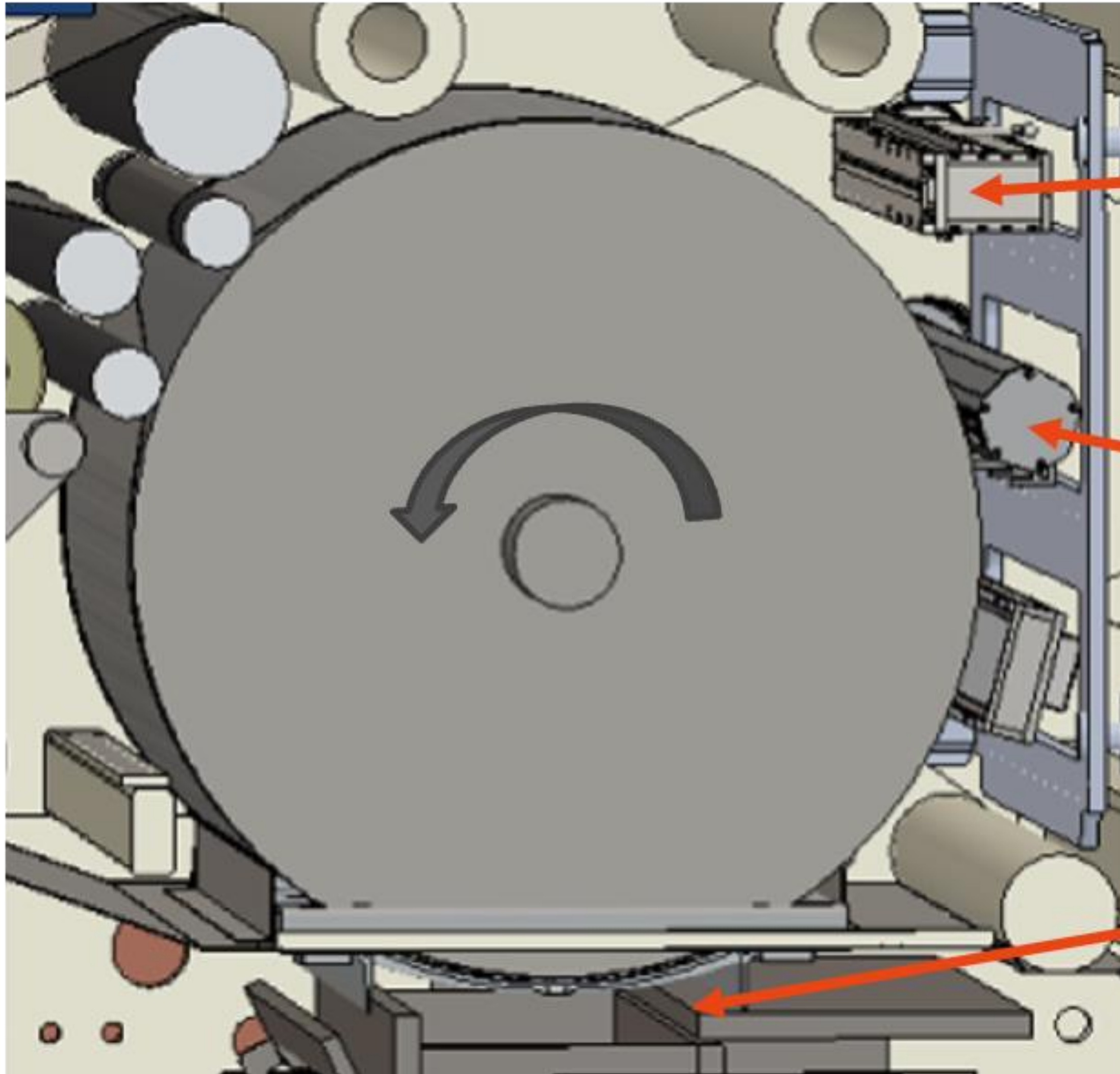
Developed color shifting pigments for currency security applications





# NanoLam™ Production Process

Bulk NanoLam™ Material Production in a single chamber.



## **NanoLam™ Dielectric Curing**

Monomer is cross-linked using an electron beam curtain

## **NanoLam™ Dielectric Deposition**

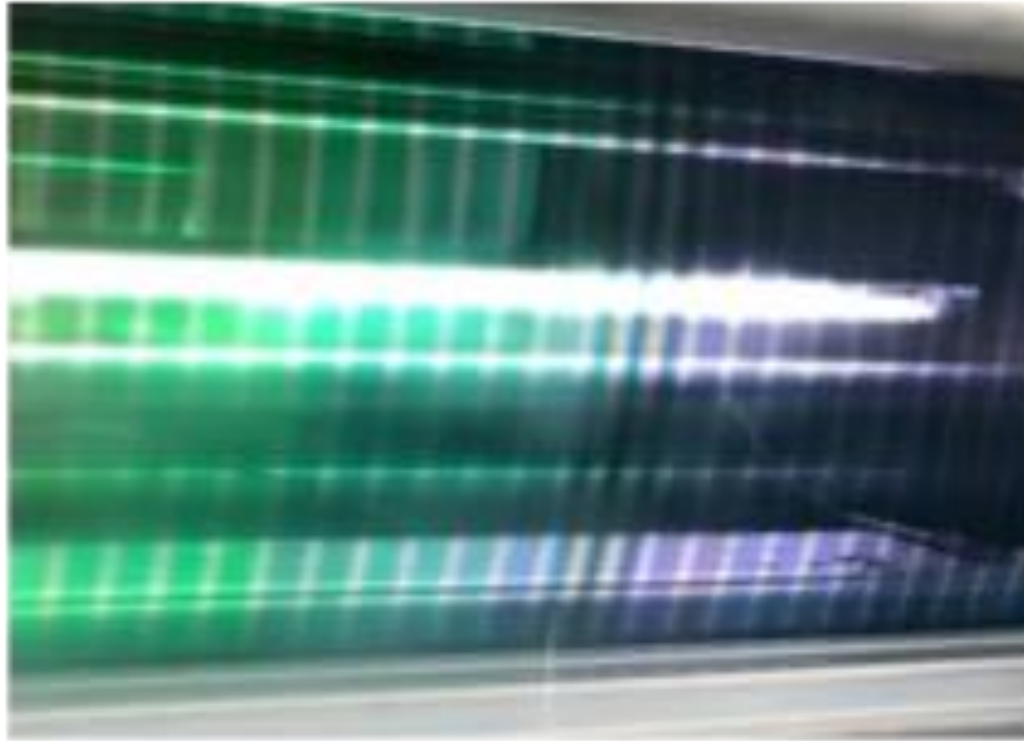
Formulated acrylate monomer are vapor deposited onto the metallized electrode.

## **Electrode Metallization**



# Nanolam™ Capacitor Process

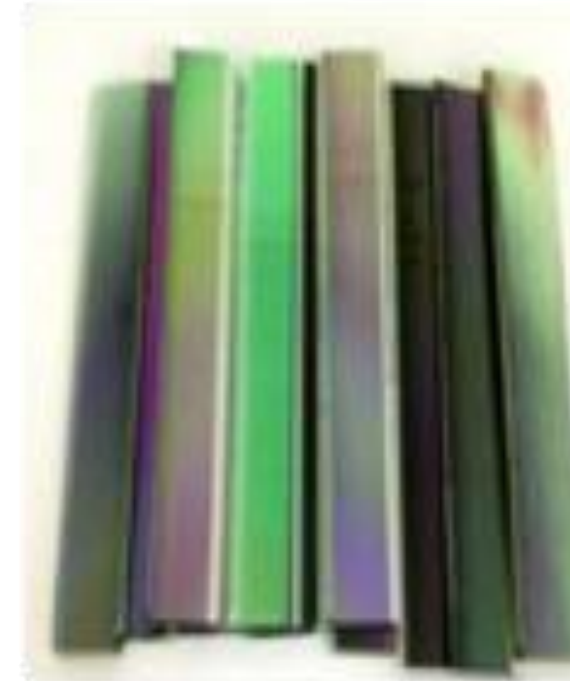
Mother Capacitor Material  
Produced on a Rotating Drum



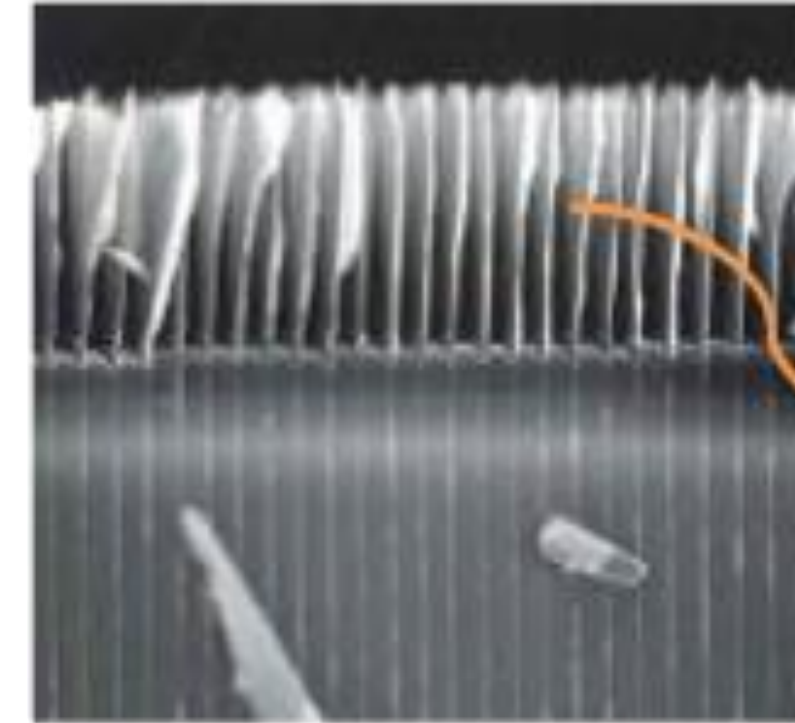
Mother Capacitor Material  
Segmented into Cards



Cards Segmented into  
Capacitor Elements



Removal of Polymer to  
Expose the Electrodes



Arc Spraying To  
Connect Electrodes in  
Parallel

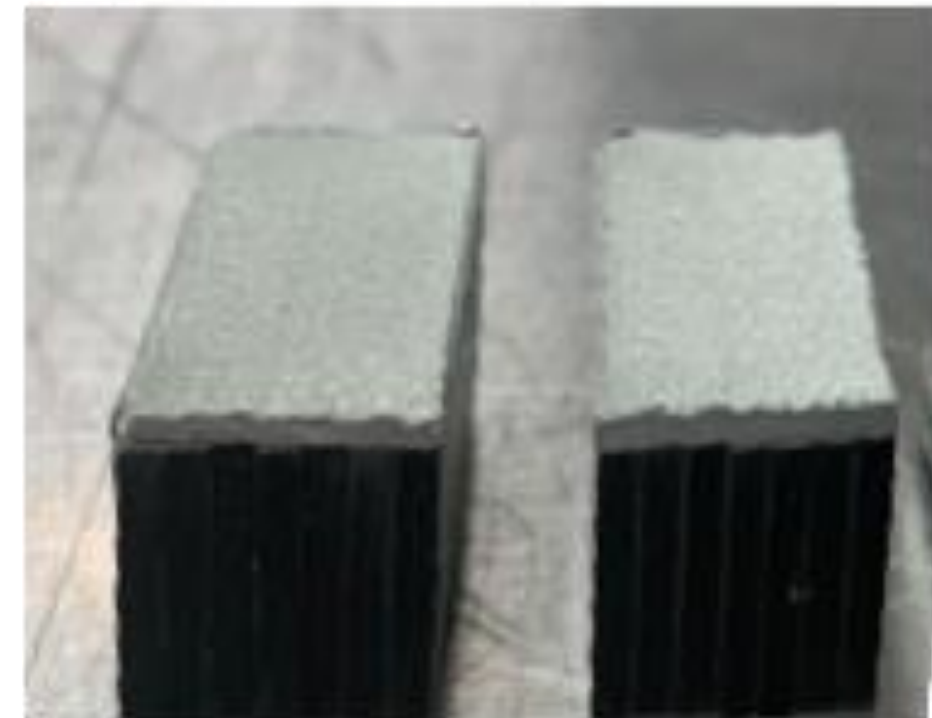


Process Flow

Fully Tested  
Capacitor Elements



Capacitor Block Formed by  
Stacked Elements



Block with Attached Bus Bar



Packaged Capacitor

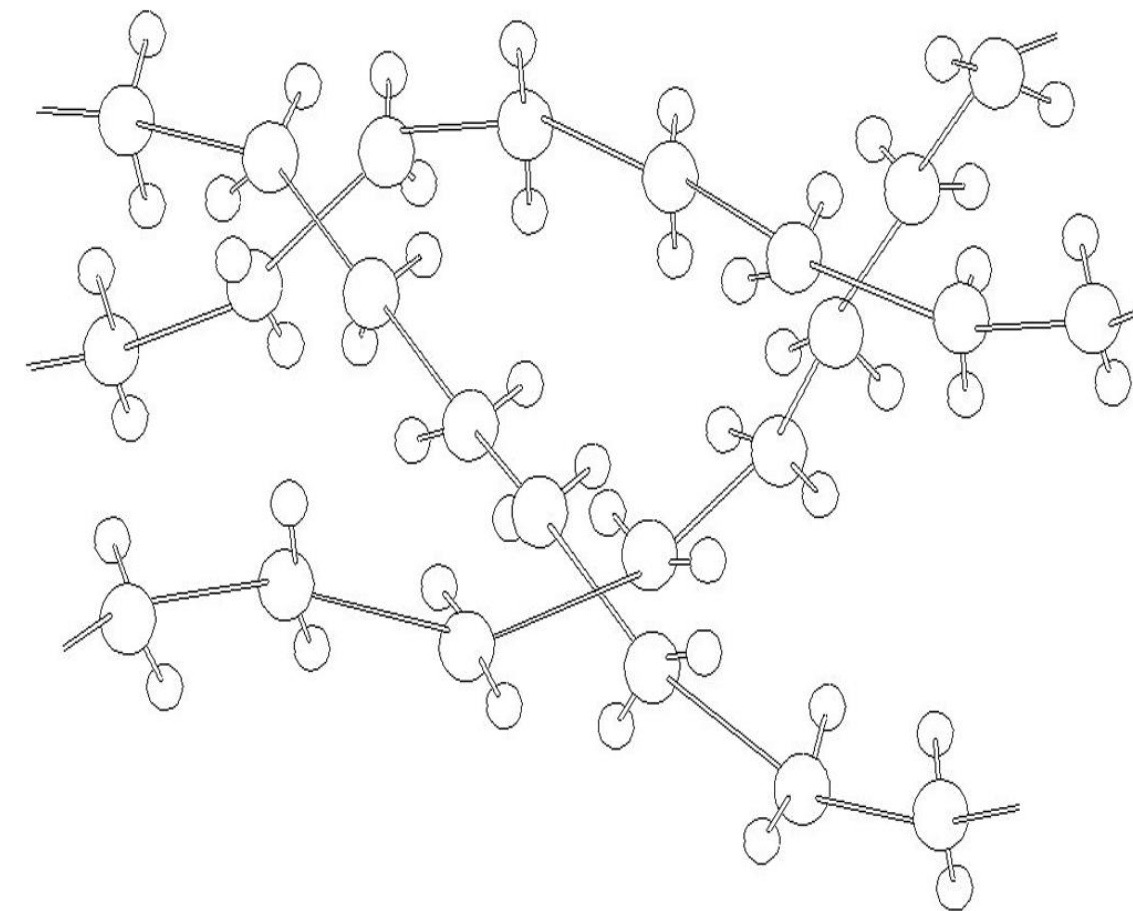
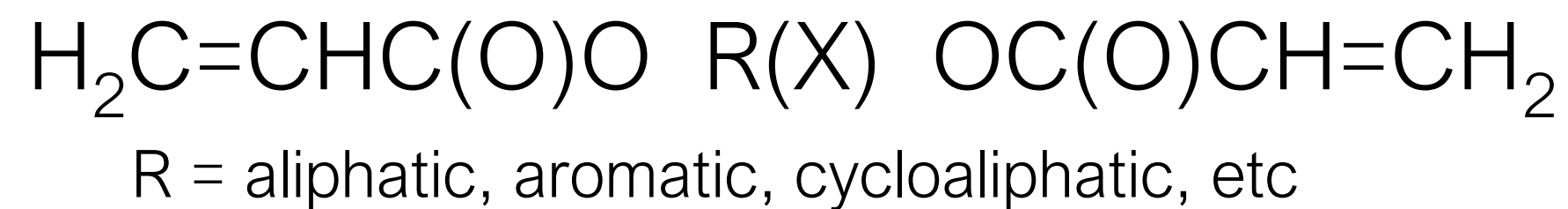




# High Temperature Polymer Dielectric Materials

## Wide Range of Chemistries

The Polymer Dielectric is Formed Using  
Electron Beam Crosslinked Acrylate Monomers  
(*Beta Radiation*)

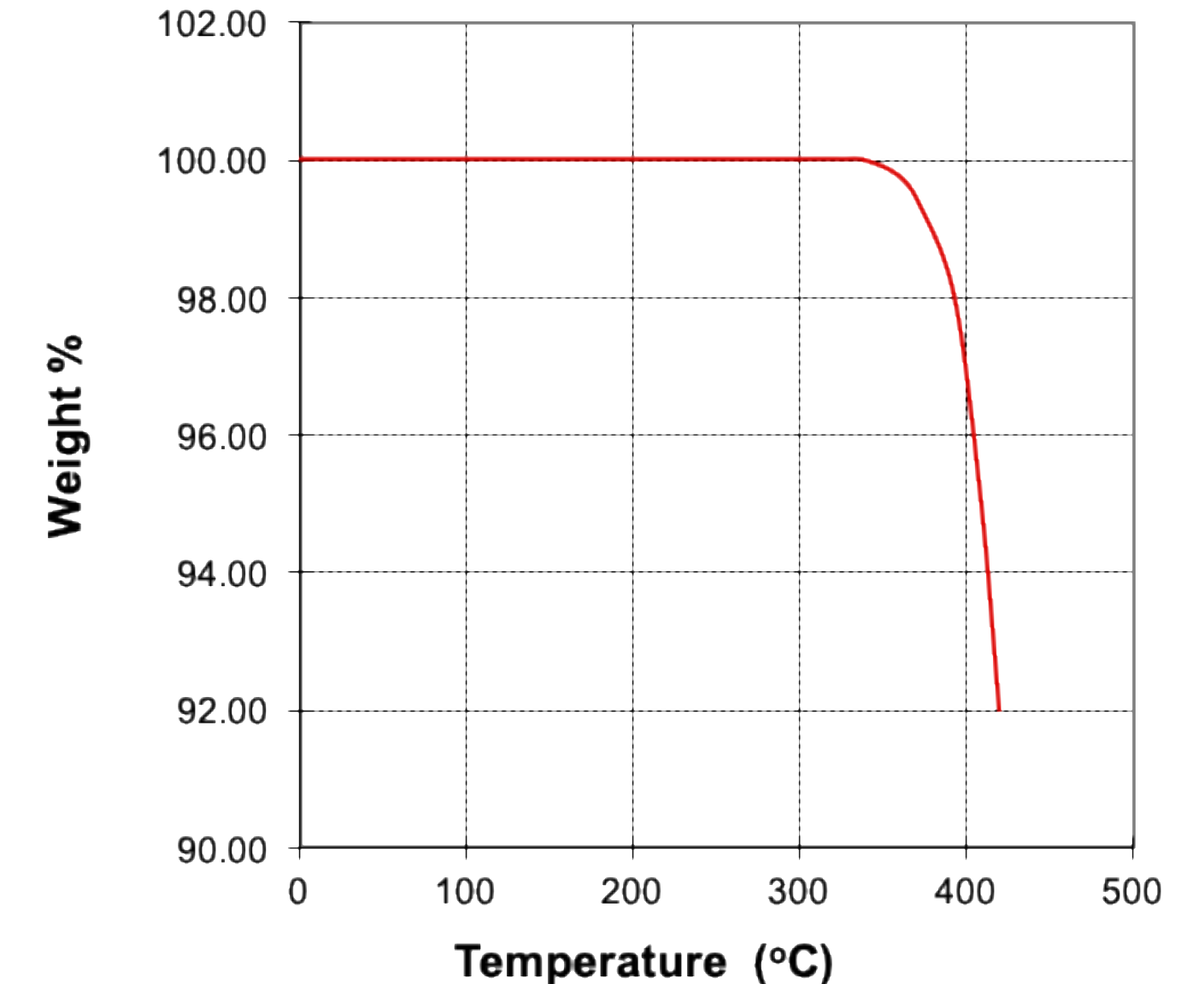


Dielectric Constants  $2.7 < k < 9$

Current NanoLam Polymer  $k=3.2$

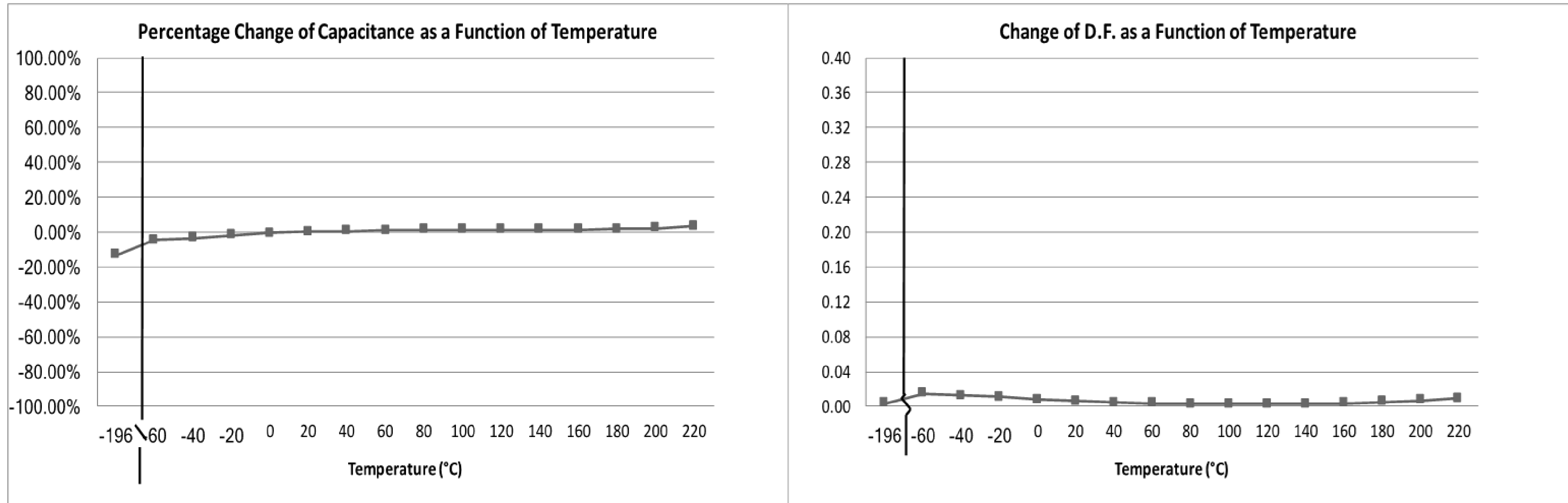
Dielectric constant of PP  $k=2.2$

Thermal Stability (TGA)





# Capacitance and Dissipation Factor Are Stable Over a Wide Temperature Range





# Controlled the Self Healing Process by Polymer Dielectric Design

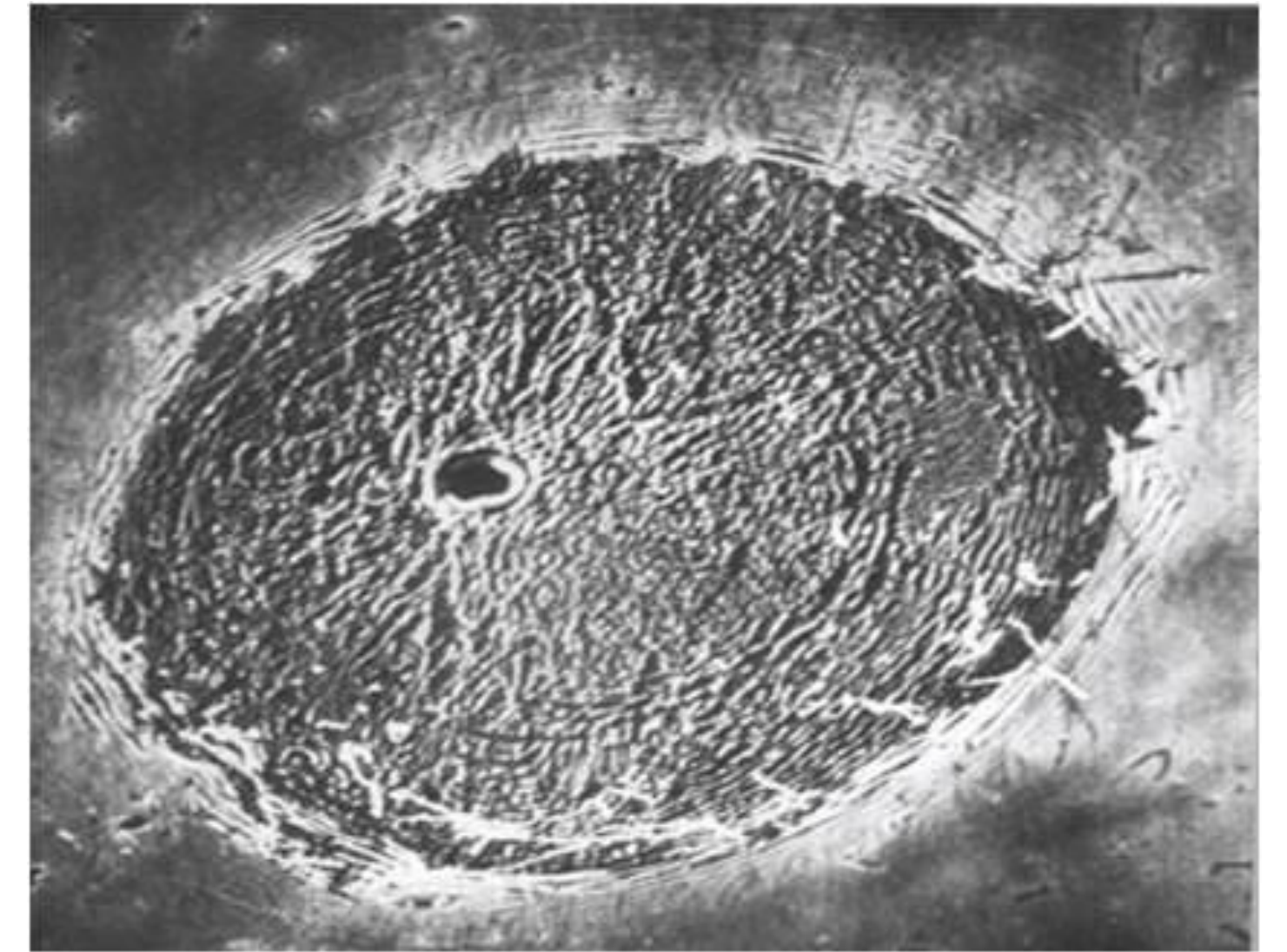
## Metallized Electrodes

Electrodes with a thick (heavy) edge are used that allow a much thinner electrode in the active capacitor electrode area to facilitate the self healing process

## Polymer Dielectric:

NanoLam capacitor dielectrics are formulated with chemistry that has specific O:C and H:C ratios. This parameter along with the electrode thickness dictates the capacitor In the active capacitor area dictate the self-healing properties

Carbon and aluminum from the breakdown site are removed by conversion to  $\text{Al}_2\text{O}_3$ , CO,  $\text{CO}_2$ ,  $\text{CH}_3$ ,  $\text{CH}_4$ , and other hydrocarbon gases.





# The Dielectric Breakdown Strength Increases as the Dielectric Thickness Decreases

The Breakdown Field is Inversely Proportional to the Dielectric Thickness

$$E_b = \frac{P_c}{J} \propto e^{-kx}$$

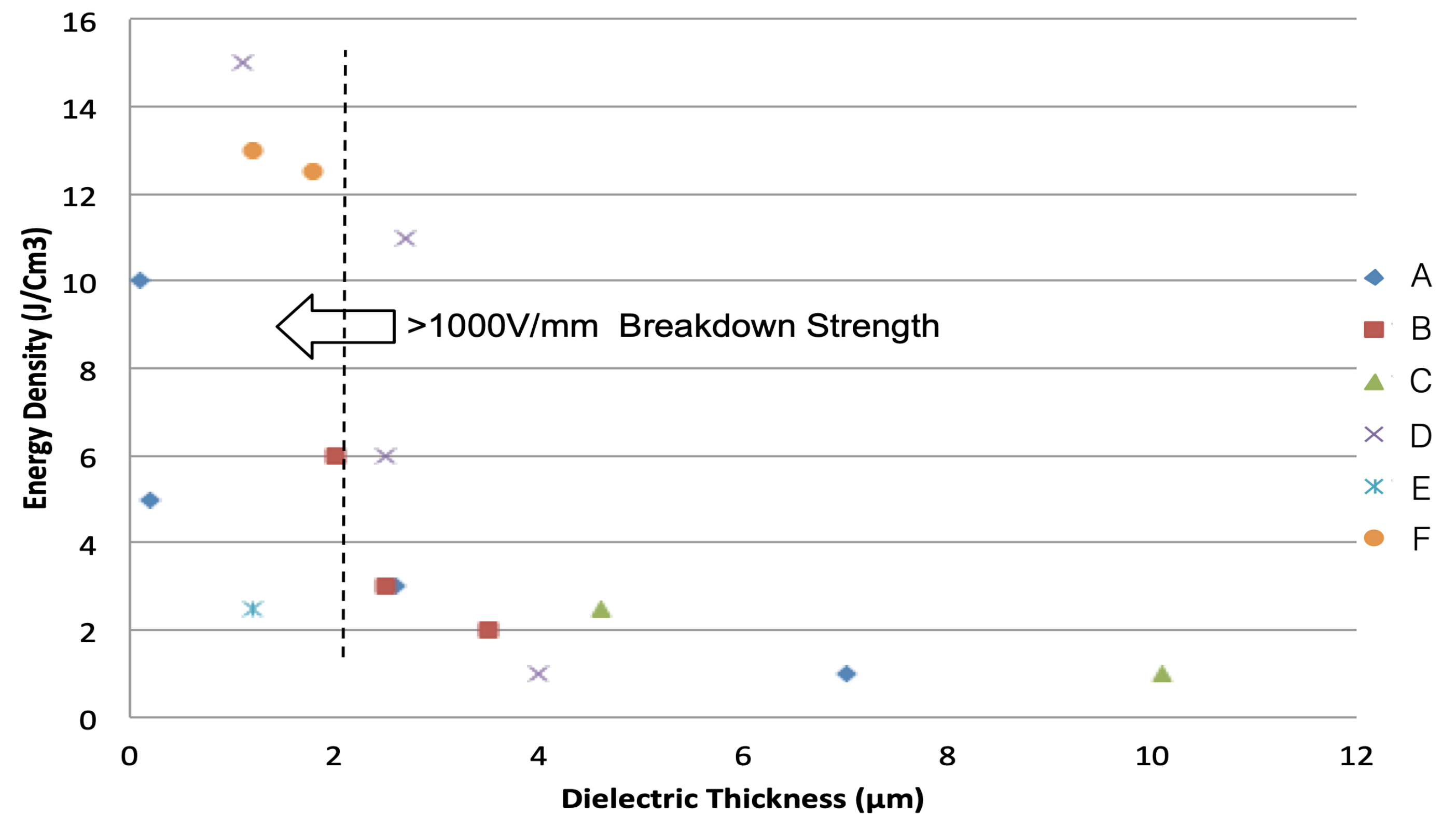
$P_c$  Critical power density at which gaseous combustion products form

$J$  = Current

$k$  = Constant

$x$  = Electrode Distance

Polymers A to F Have Dielectric Constants  $k$  in the range  $3 > k < 9$





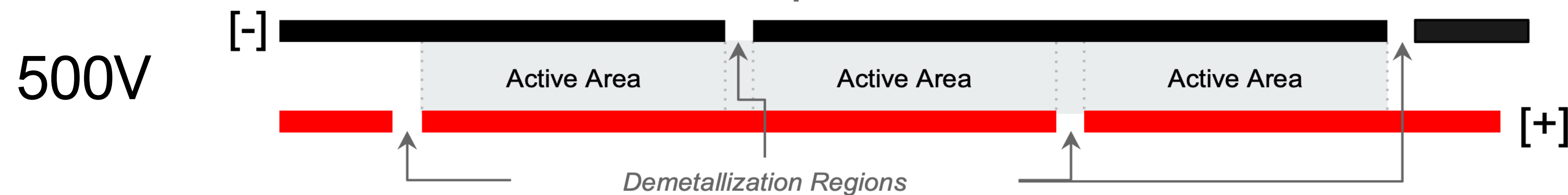
In order to Take Advantage of the High Breakdown Strength of the Nanothick Dielectric Layers Higher Voltage Capacitors are made with Internal Series Sections  
Capacitors are routinely produced with voltages in the range of 48V to 5000V

## Common DC-Link capacitor Designs

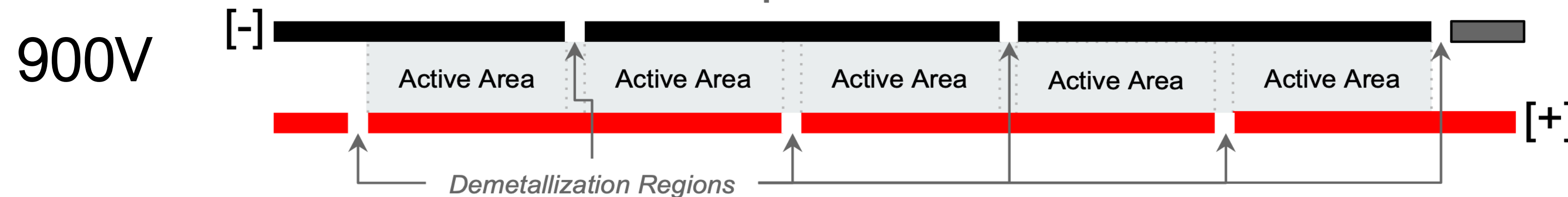
### Single Capacitor



### 3 Internal Capacitors Connected in Series

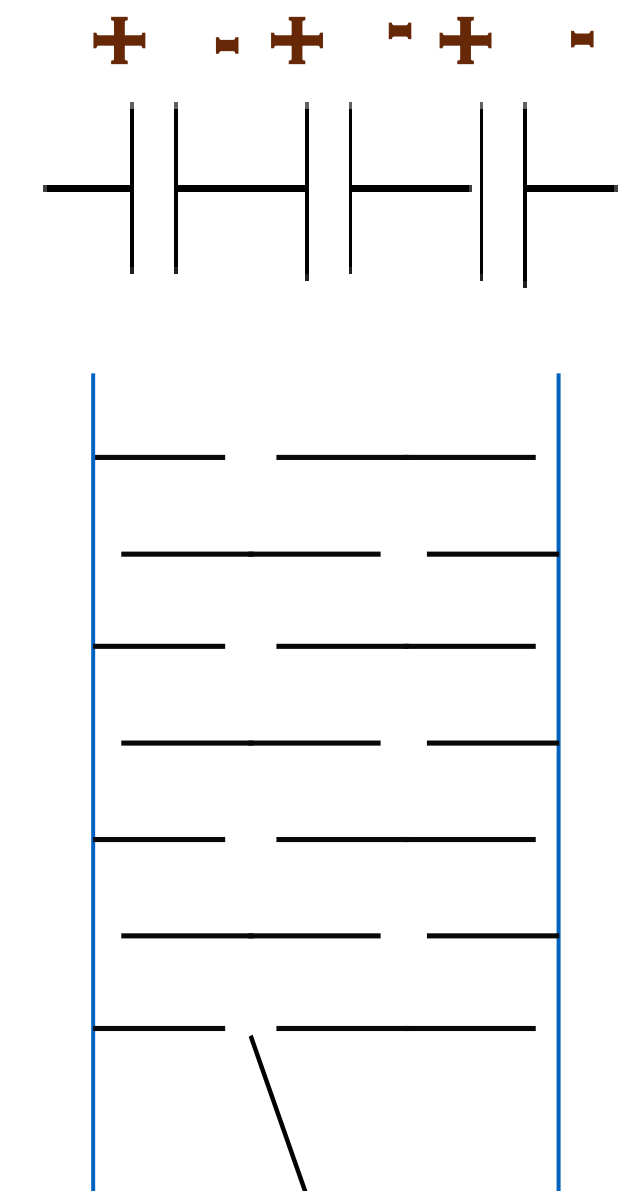
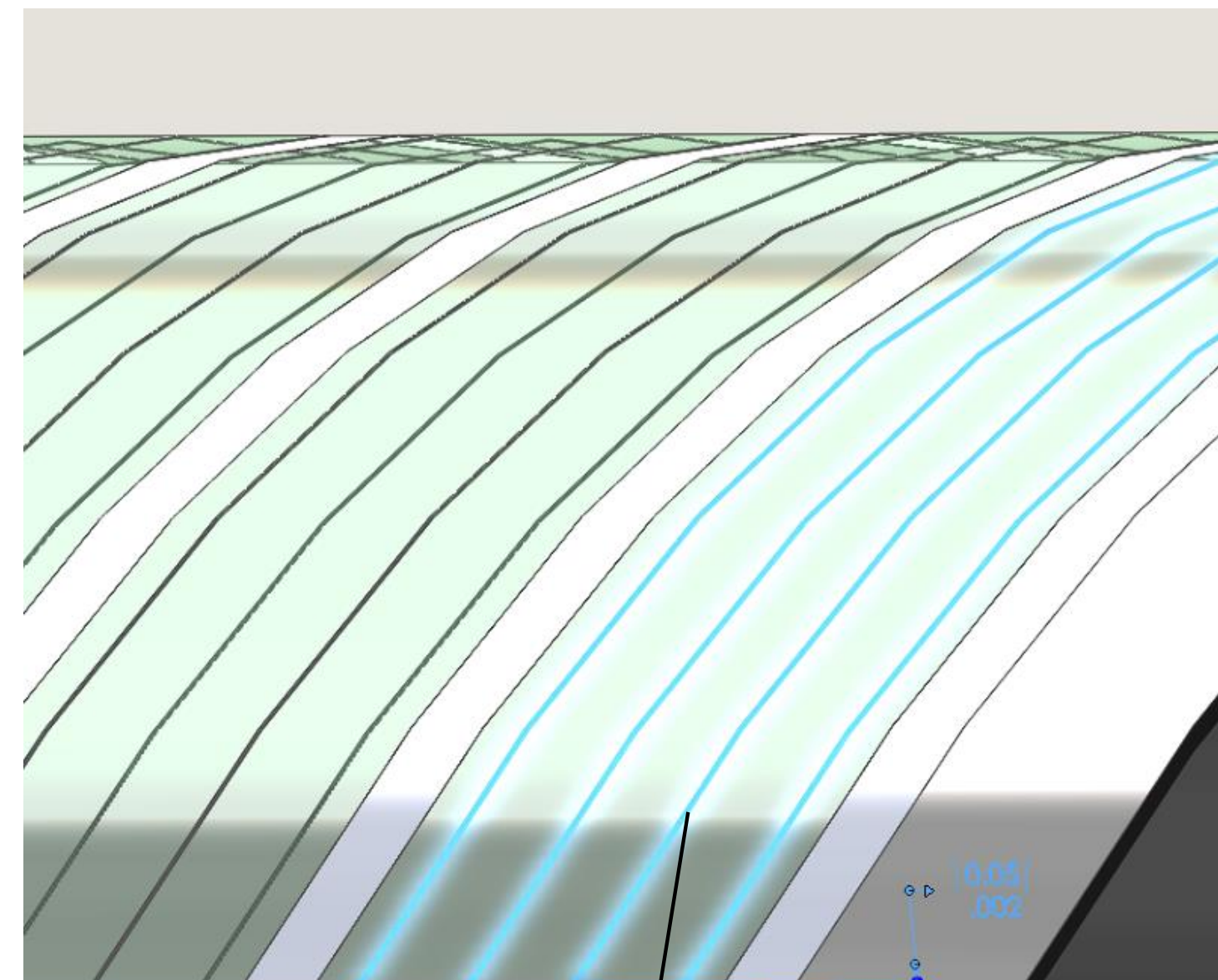


### 5 Internal Capacitors Connected in Series





# Higher Voltage Capacitors with Multiple Internal Series Sections are Produced In-situ in the Vacuum Chamber on the Process Drum



Oil Generated Demetallization Areas to Form Series Capacitors



# Energy Buffer 4400 $\mu$ F NanoLam Capacitors Produced for a NASA Dynamic Radioisotope Power System (DRPS)

Solid State Polymer  
NanoLam™ Capacitor  
50V/4400 $\mu$ F,  
-55°C to +125°C

**Energy Density = 0.1J/cc**

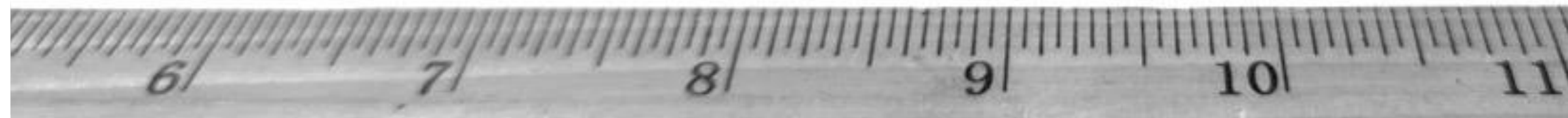
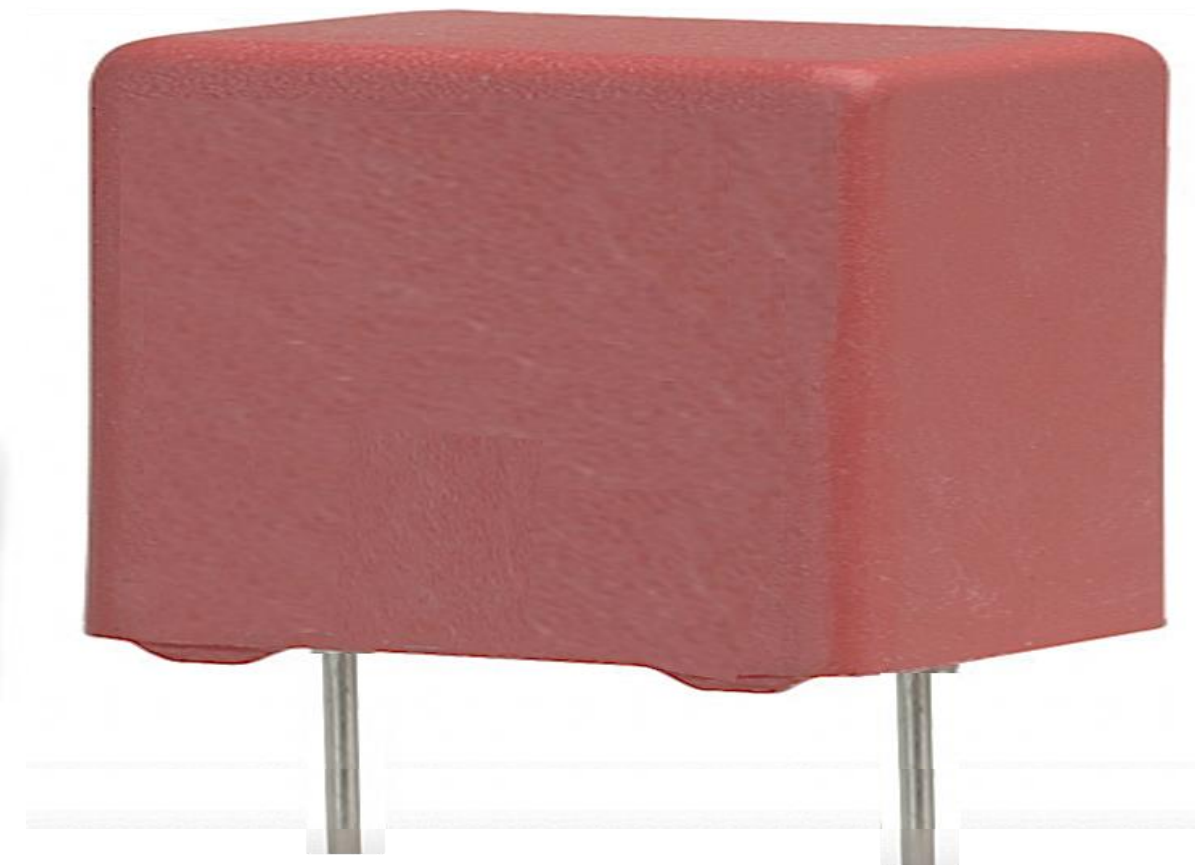
W:28mm H:33mm L:61mm



State of the Art  
Wound Film Capacitor  
50V/680 $\mu$ F,  
-55°C to +105°C

**Energy Density = 0.006J/cc**

W:45mm H:55mm L:57mm





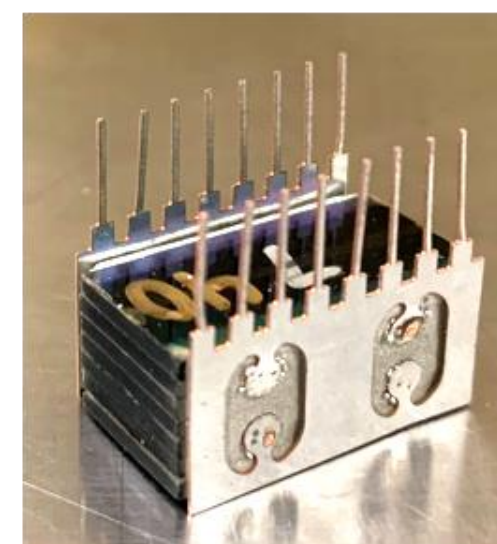
# DC-link 500V NanoLam Capacitors Developed for a NASA Ion Thruster PPU to Replace 500V X7R Capacitors that Were Microcracking and Shorting

## Property

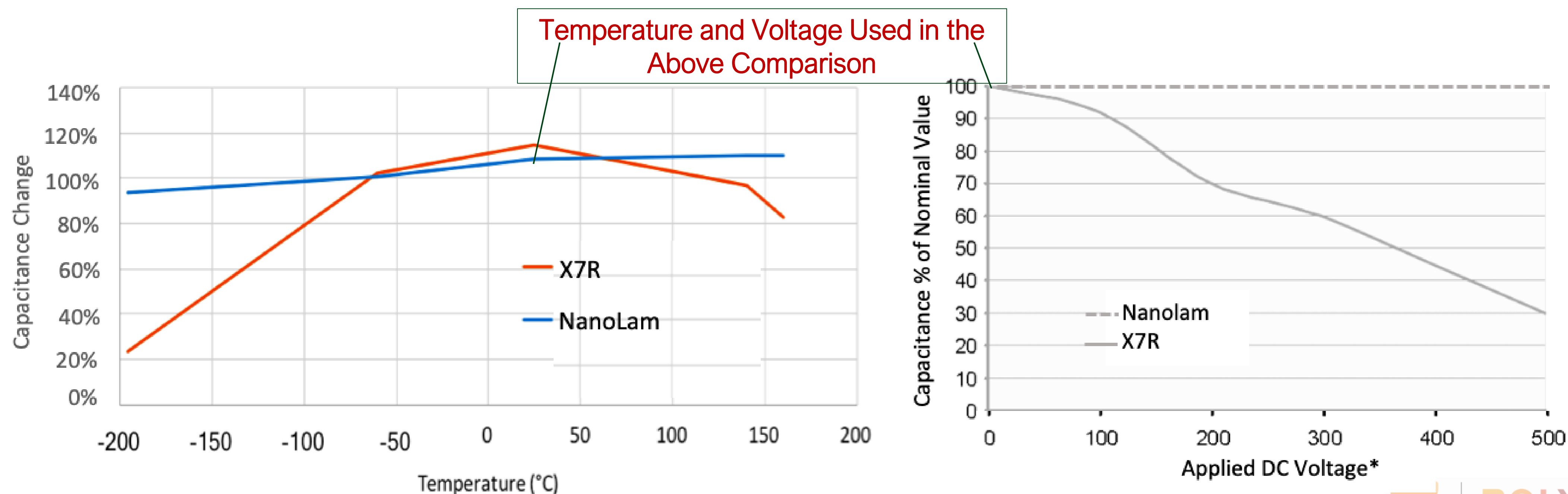
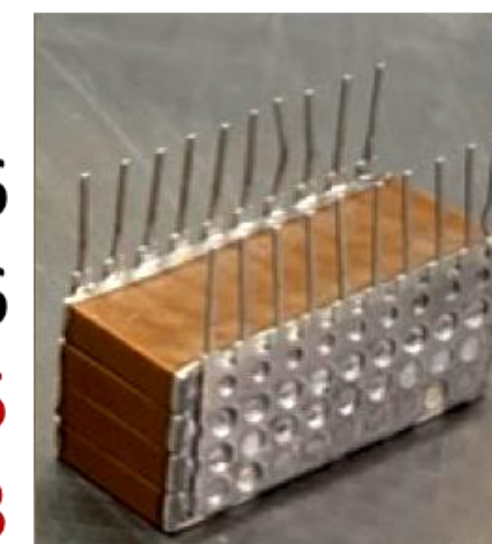
## NanoLam

## X7R

Capacitance $\mu\text{F}$	15.2
Volume cc	2.0
Weight gr	3.8
Energy Density J/cc	0.95 (3.8X)
Specific Energy J/gr	0.50 (16X)



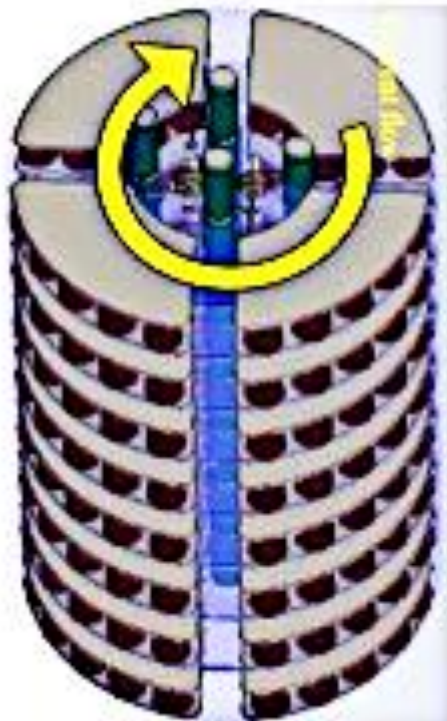
5.7
2.86
20.6
0.25
0.03



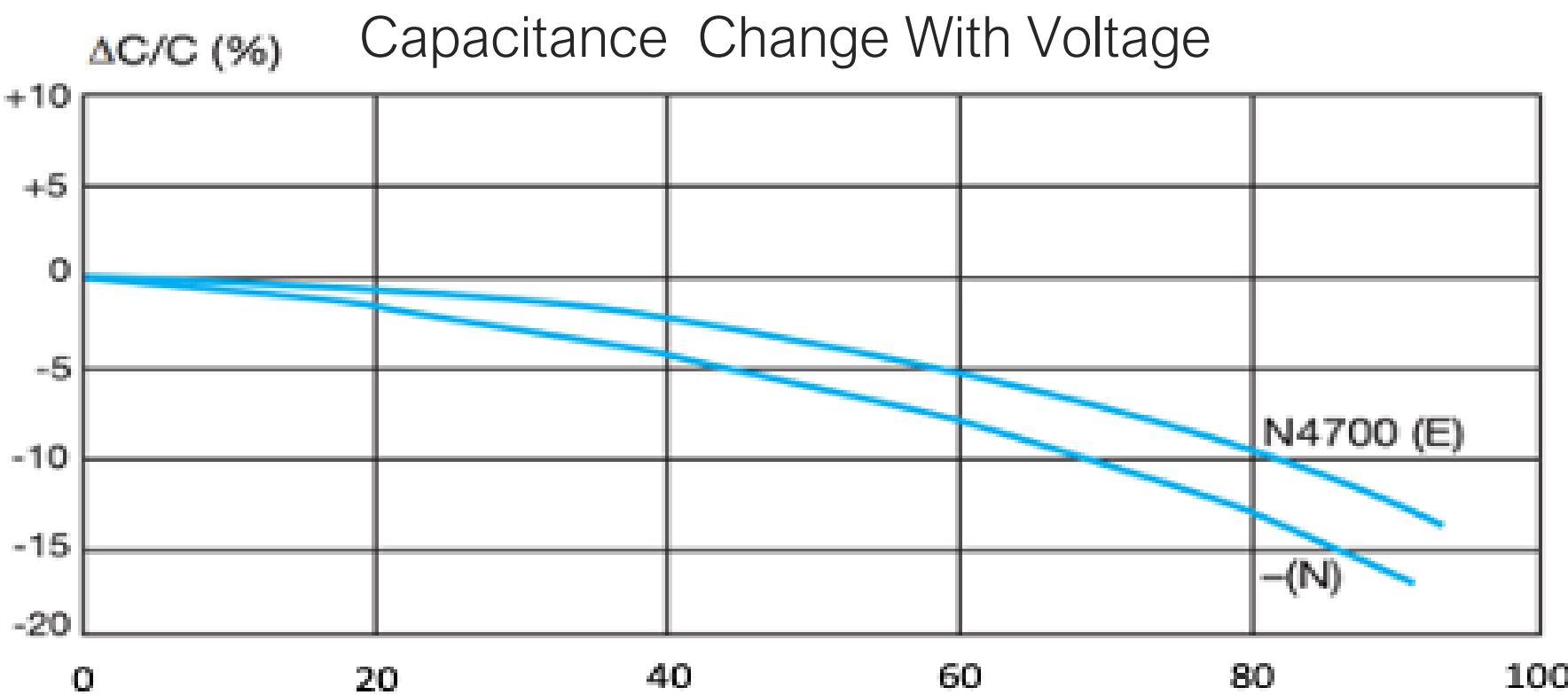
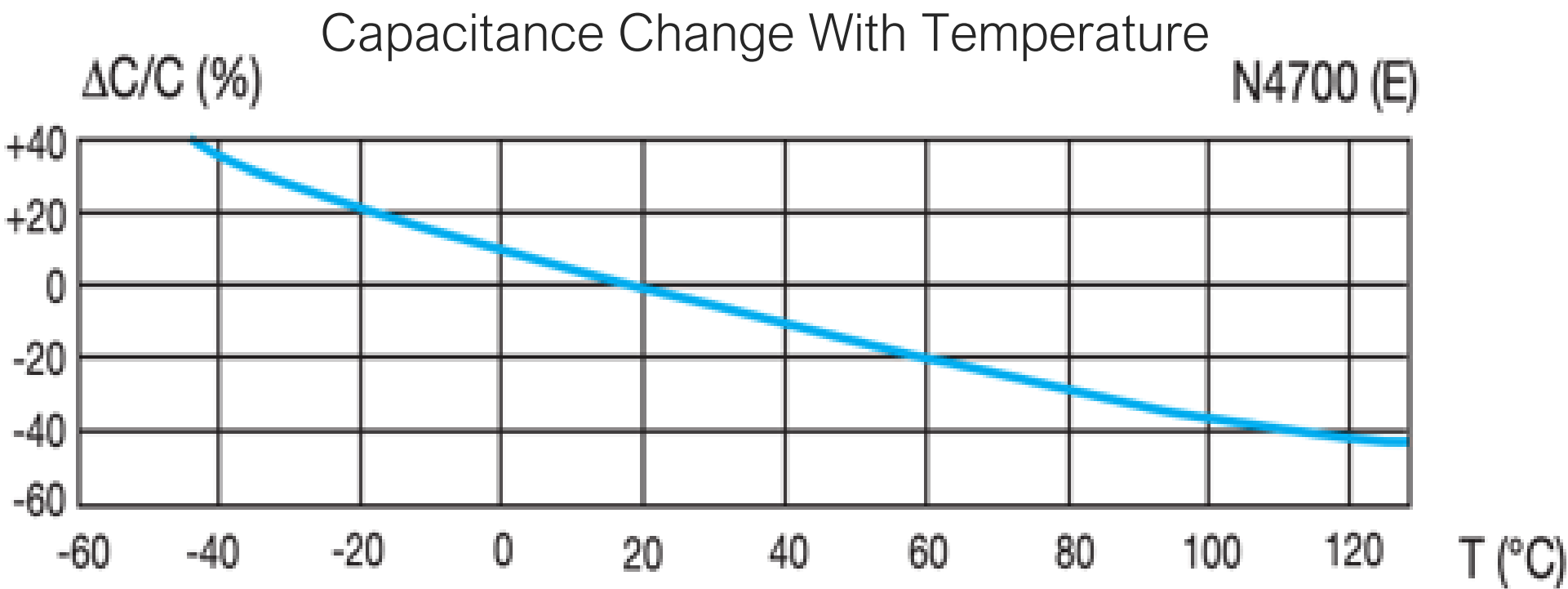
\* This property can vary somewhat from OEM to OEM

# HV Pulse Power Capacitors

Ceramic Capacitor Banks  
used for HV Pulse Power  
Applications



Ceramic Capacitance Change with Temperature and Bias  
Operating temperature -30C to +85°C



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Typical State of the Art  
Ceramic Capacitor  
40KV/C=1.3nF  
D=45mm, H =25mm  
W-175gr

Energy Density  
0.023 J/cc

Specific Energy  
0.006 J/gr



5KV/40nF

L=37mm x H-1.6mm W=10mm



40KV/5nF

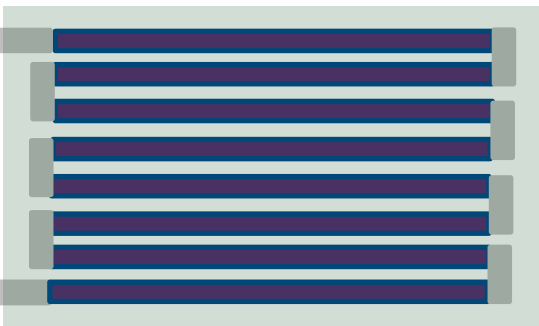
W=10mm, H=1.6mm, L=298mm

Weight: 4gr

Energy Density  
0.48 J/cc

Specific Energy  
0.20 J/gr

40KV



0V

Packaged Design  
5KV/40nF capacitor  
20gr

> 20X Energy Density

> 25X Specific Energy

Not Including Capacitance Loss  
Due to Temperature and Voltage



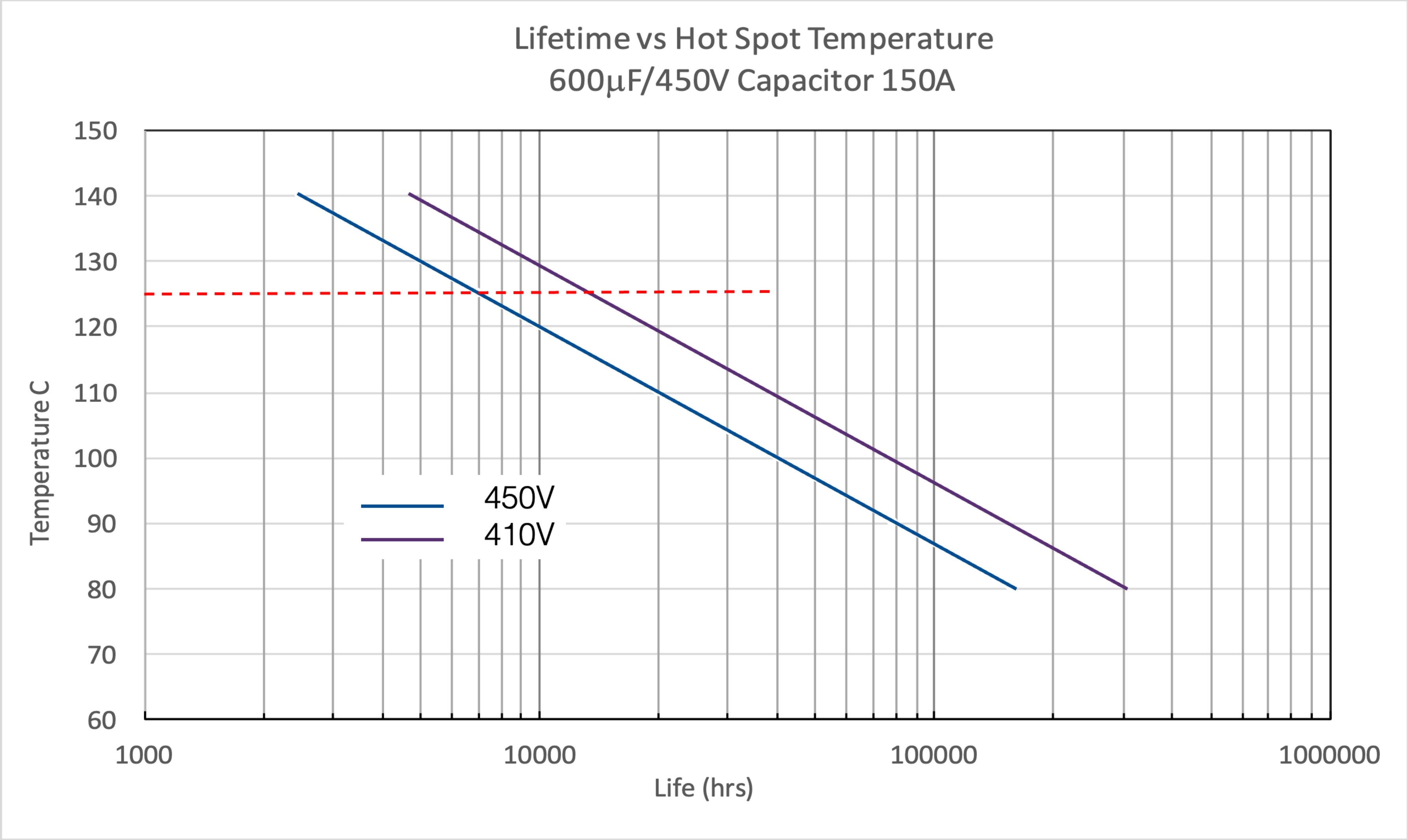
Given That We Control All Material and Process Parameters  
NanoLam Capacitors Can be Customized for a Variety of Applications



Pulse Capacitor for a Medical Application  
 $140\mu\text{F}/2200$   
Energy Density:  $6.3 \text{ J/cc}$

# Example of Life Of High Current 450V DC-link NanoLam Capacitors

End of Life = 5% Capacitance Loss





## CONCLUSIONS

When compared to polymer film and Ceramic Multilayer capacitors

- High temperature polymer dielectric
- High Breakdown strength dielectric layers
- Optimized O:C and H:C chemistry to maximize self-healing performance
- High thermal conductivity
- High energy density and Specific Energy
- High RMS ripple current capacity and excellent dV/dt performance
- Manufactured using a single step process allowing control most key capacitor parameters including:
  - Dielectric thickness
  - Dielectric constant
  - Glass transition temperature
  - Self-healing properties
  - Electrode metallization

